

BOURNS®

Features

- Formerly FulTec brand
- Extremely high speed performance
- Blocks high voltages and currents
- Very high bandwidth; GHz compatible
- Small package, minimal PCB area
- Simple, superior circuit protection
- RoHS compliant*, UL Recognized

The C650 & C850 Series are currently available, but not recommended for new designs. Bourns® TBU-CA Series is preferred.

C650 and C850 Series TBU® High-Speed Protectors

Transient Blocking Units - TBU® Devices

Bourns® C650 and C850 series products are high-speed bidirectional protection components, constructed using MOSFET semiconductor technology, designed to protect against faults caused by short circuits, AC power cross, induction and lightning surges.

The TBU® high-speed protector, triggering as a function of the MOSFET, blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events. The TBU® device is provided in a surface mount DFN package and meets industry standard requirements such as RoHS and Pb Free solder reflow profiles.

Agency Approval

UL recognized component File # E315805.

Industry Standards

Description			Model
Telcordia	GR-1089	Port Type 1, 3, 5	C650 C850
	GR-974		C650 C850
ITU-T	K.20, K.20E, K.21, K.21E, K.45		C850

Absolute Maximum Ratings (T_{amb} = 25 °C)

Symbol	Parameter		Value	Unit
V_{imp}	Maximum protection voltage for impulse faults with rise time ≥ 1 µsec	C650-xxx-WH C850-xxx-WH	650 850	V
V_{rms}	Maximum protection voltage for continuous V_{rms} faults	C650-xxx-WH C850-xxx-WH	300 425	V
T_{op}	Operating temperature range		-40 to +85	°C
T_{stg}	Storage temperature range		-65 to +150	°C

Electrical Characteristics (T_{amb} = 25 °C)

Symbol	Parameter		Min.	Typ.	Max.	Unit
I_{op}	Maximum current through the device that will not cause current blocking	Cx50-100-WH Cx50-180-WH Cx50-260-WH			100 180 260	mA
$I_{trigger}$	Typical current for the device to go from normal operating state to protected state	Cx50-100-WH Cx50-180-WH Cx50-260-WH		150 220 330		mA
I_{out}	Maximum current through the device	Cx50-100-WH Cx50-180-WH Cx50-260-WH			200 360 520	mA
R_{device}	Series resistance of the TBU® device	C650-100-WH C650-180-WH C650-260-WH C850-100-WH C850-180-WH C850-260-WH		12 8 8 17 11 11	14.5 10 10 19 14 14	Ω
t_{block}	Maximum time for the device to go from normal operating state to protected state				1	µs
$I_{quiescent}$	Current through the triggered TBU® device with 50 Vdc circuit voltage			1		mA
V_{reset}	Voltage below which the triggered TBU® device will transition to normal operating state			14		V

C650 and C850 TBU® High-Speed Protectors are bidirectional; specifications are valid in both directions.

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.
Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

Applications

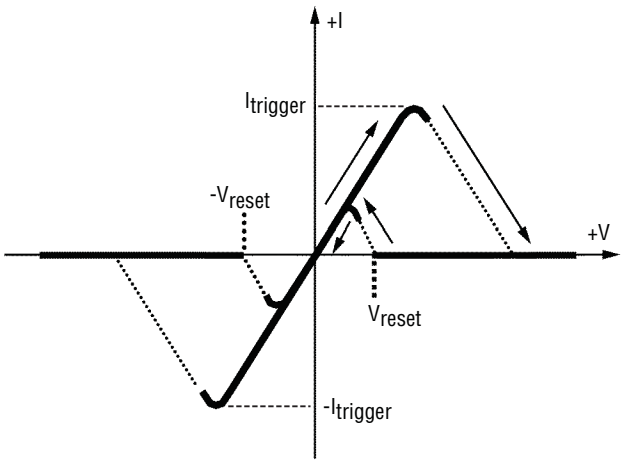
- Combo voice / xDSL linecards
- Voice linecards
- MDF, primary protection modules
- Process control equipment
- Test and measurement equipment
- General electronics

C650 and C850 Series TBU® High-Speed Protectors

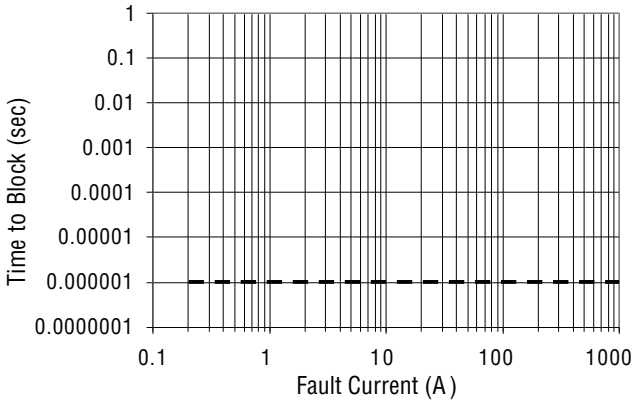
BOURNS®

Typical Performance Characteristics

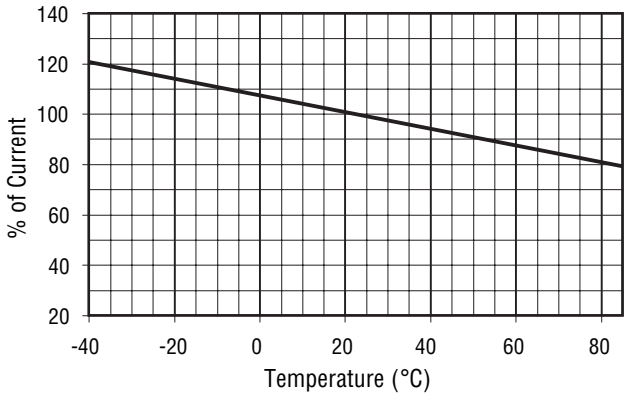
V-I Characteristics



Time to Block vs. Fault Current



Current vs. Temperature

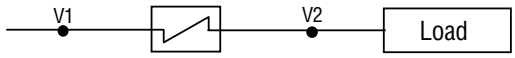


Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

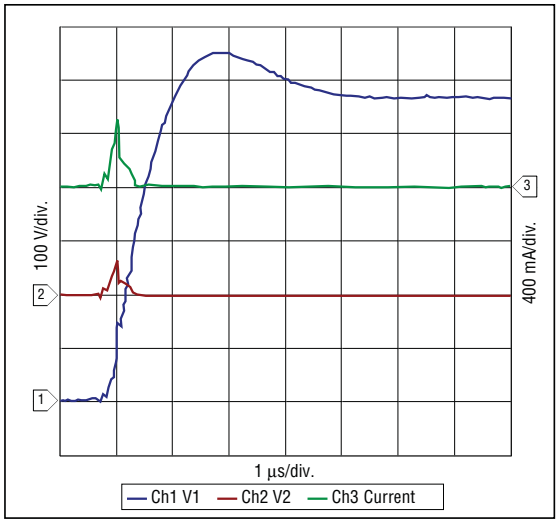
Operational Characteristics

The graphs below demonstrate the operational characteristics of the TBU® protector. For each graph the fault voltage, protected side voltage, and current is presented.

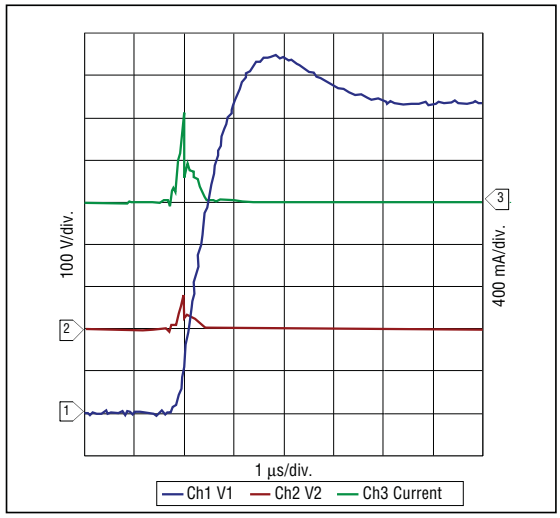
TEST CONFIGURATION DIAGRAM



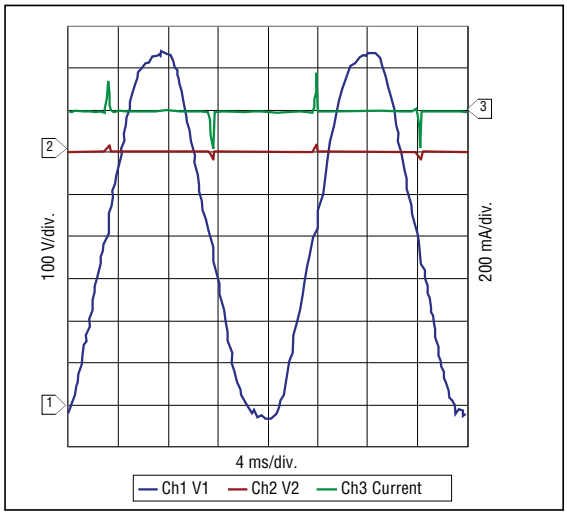
C650 Lightning, 650 V



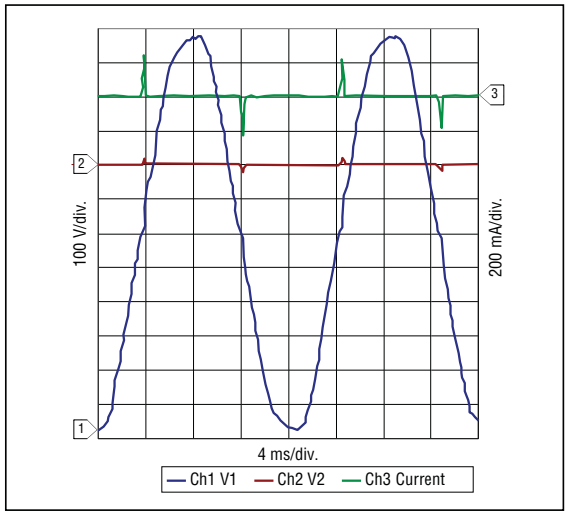
C850 Lightning, 850 V



C650 Power Fault, 300 Vrms, 100 A

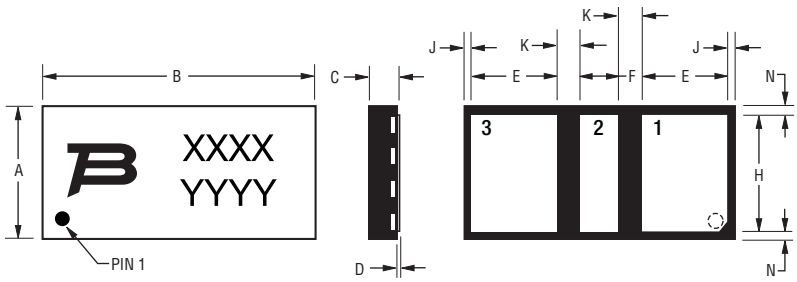


C850 Power Fault, 425 Vrms, 100 A



Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

Product Dimensions

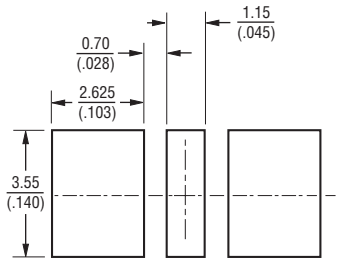


TOP VIEW SIDE VIEW BOTTOM VIEW

Dim.	Min.	Typ.	Max.
A	3.90 (.154)	4.00 (.157)	4.10 (.161)
B	8.15 (.321)	8.25 (.325)	8.35 (.329)
C	0.80 (.031)	0.85 (.033)	0.90 (.035)
D	0.000 (.000)	0.025 (.001)	0.050 (.002)
E	2.55 (.100)	2.60 (.102)	2.65 (.104)
F	1.10 (.043)	1.15 (.045)	1.20 (.047)
H	3.45 (.136)	3.50 (.138)	3.55 (.140)
J	0.20 (.008)	0.25 (.010)	0.30 (.012)
K	0.65 (.026)	0.70 (.028)	0.75 (.030)
N	0.20 (.008)	0.25 (.010)	0.30 (.012)

DIMENSIONS: MM (INCHES)

Recommended Pad Layout



Pad Designation

Pad #	Apply
1	In/Out
2	NC
3	In/Out

NC = Solder to PCB; do not make electrical connection, do not connect to ground.

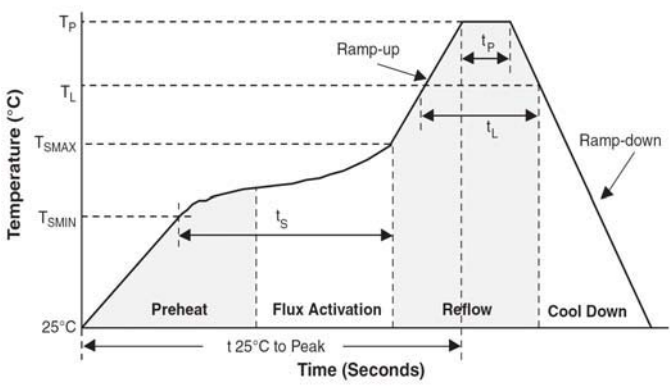
TBU® protectors have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to leads (package)	116	°C/W

Reflow Profile

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Tsmax to Tp)	3 °C/sec. max.
Preheat - Temperature Min. (Tsmin) - Temperature Max. (Tsmax) - Time (tsmin to tsmax)	 150 °C 200 °C 60-180 sec.
Time maintained above: - Temperature (TL) - Time (tL)	 217 °C 60-150 sec.
Peak/Classification Temperature (Tp)	260 °C
Time within 5 °C of Actual Peak Temp. (tp)	20-40 sec.
Ramp-Down Rate	6 °C/sec. max.
Time 25 °C to Peak Temperature	8 min. max.



Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

C650 and C850 Series TBU® High-Speed Protectors

BOURNS®

How to Order

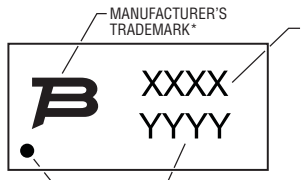
C 650 - 180 - WH

Form Factor
- C = One TBU® protector in the device

Impulse Voltage Rating
- 650 = 650 V
- 850 = 850 V

Iop Indicator
- 100 = 100 mA
- 180 = 180 mA
- 260 = 260 mA

Typical Part Marking



MARKING NUMBER
- C65A = C650-100-WH
- C65B = C650-180-WH
- C65C = C650-260-WH
- C85A = C850-100-WH
- C85B = C850-180-WH
- C85C = C850-260-WH

- 1ST DIGIT INDICATES THE YEAR'S 6-MONTH PERIOD.
- 2ND DIGIT INDICATES THE WEEK NUMBER IN THE 6-MONTH PERIOD.
- 3RD & 4TH DIGITS INDICATE SPECIFIC LOT FOR THE WEEK.

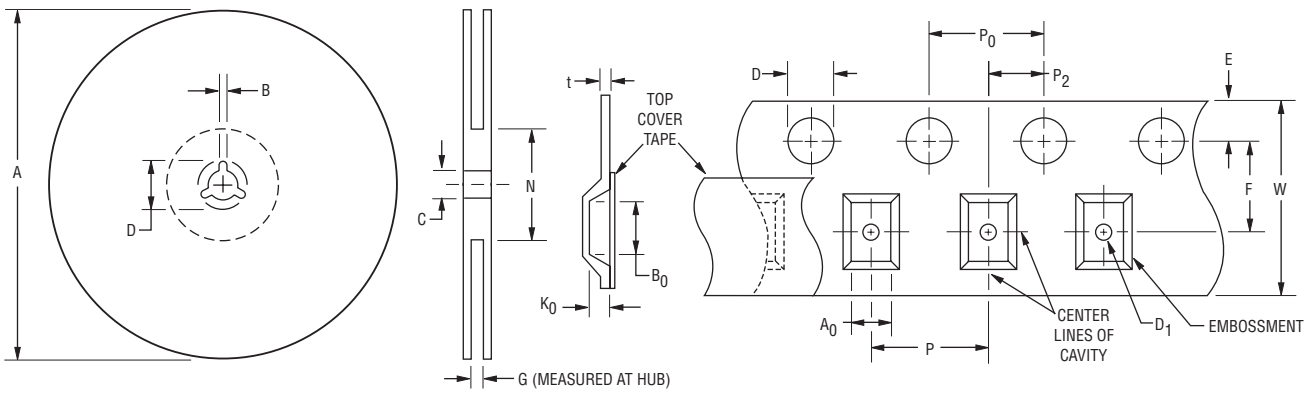
6-MONTH PERIOD CODES:

A = JAN-JUN 2009	C = JAN-JUN 2010	E = JAN-JUN 2011
B = JUL-DEC 2009	D = JUL-DEC 2010	F = JUL-DEC 2011

EXAMPLE: ARBC
- *1ST DIGIT 'A' = JAN-JUN 2009*
- *2ND DIGIT 'R' = WEEK 18; WEEK OF APRIL 27*
- *3RD & 4TH DIGITS 'BC' = LOT SPECIFIC INFORMATION*

*TRANSITION FROM FULTEC TRADEMARK AND LOT CODE TO BOURNS TRADEMARK AND DATE CODE IN 2009.

Packaging Specifications (per EIA468-B)



QUANTITY: 3000 PIECES PER REEL

Device	A		B		C		D		G	N
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Ref.	Ref.
C650, C850	326 (12.835)	330.25 (13.002)	1.5 (.059)	2.5 (.098)	12.8 (.504)	13.5 (.531)	20.2 (.795)	-	16.5 (.650)	102 (4.016)

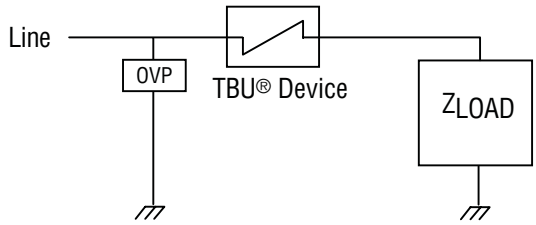
Device	A_0		B_0		D		D_1		E		F	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	max.
C650, C850	4.2 (.165)	4.4 (.173)	8.45 (.333)	8.65 (.341)	1.5 (.059)	1.6 (.063)	1.5 (.059)	-	1.65 (.065)	1.85 (.073)	7.4 (.291)	7.6 (.299)
Device	K_0		P		P_0		P_2		t		W	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
C650, C850	1.1 (.043)	1.3 (.051)	7.9 (.311)	8.1 (.319)	3.9 (.159)	4.1 (.161)	1.9 (.075)	2.1 (.083)	0.25 (.010)	0.35 (.014)	15.7 (.618)	16.3 (.642)

DIMENSIONS: MM (INCHES)

Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

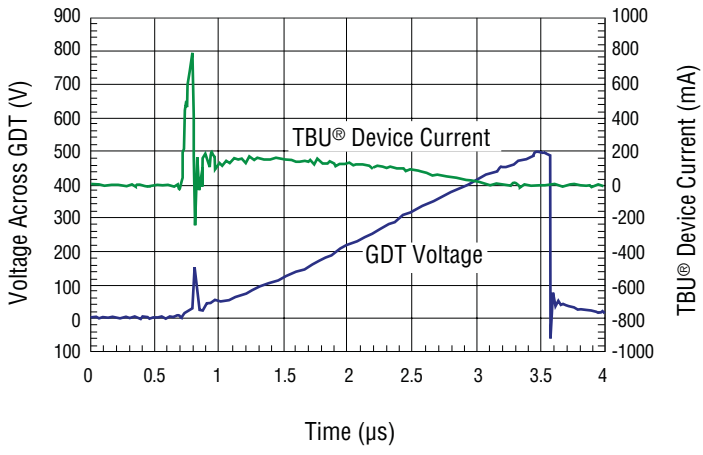
Reference Application

The C-series devices are general protectors that can be used in a variety of applications. The basic operation of the device will be demonstrated using the single line application shown in the figure below. The test circuit was subjected to a 1000 V, 10/700 μs surge waveform. The devices used were the TBU-C850-100-WH and a 2031-42T-SM-RPLF GDT (OVP) with a 10 ohm resistor for the load impedance.



General Application Circuit

The graph below shows the waveforms for the voltage across the overvoltage protector (GDT) and the current through the TBU® device. As the input line voltage increases, the current through the TBU® device increases rapidly until the trip current is reached. Due to finite reaction time for fast transients, the peak level may exceed the low frequency data sheet maximum for a very short period, typically ~100 ns. After this initial overshoot, the TBU® device will transition to the protected state, setting the current to the nominal current limiting level (~150 mA for this example). The TBU® device will then reduce the current down it to its very low quiescent level of 1 mA, typically. As the input line voltage increases to about 500 V, the GDT is triggered, reducing the input line voltage to a very low level which prevents the TBU® device from being subjected to a voltage level which exceeds its maximum rating (850 V in this example). The TBU® High-Speed Orotector and the GDT will remain in these states until the surge ends, which is about 700 μs later in this example. Only the first 4 μs of the surge are shown in the graph. For surges or AC voltages below the GDT breakover voltage, the GDT will not activate, and the TBU® device will stay in the protecting mode, blocking high voltages from the protected equipment.



TBU-C850-100-WH Response to a 1000 V, 10/700 μs Surge

"TBU" is a registered trademark of Bourns, Inc. in the United States and other countries.
Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

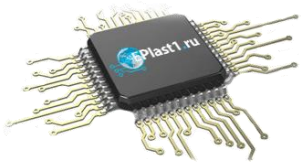
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.